

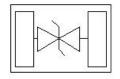
SSCE5V022L1

1-Line Bidirectional TVS Diode

Description

The SSCE5V022L1 is designed with SSC process TVS technology to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium.

PIN configuration



Top view



Marking

Feature

- \Rightarrow 80W peak pulse power (tP = 8/20 μ s)
- ♦ DFN0603-2L Package
- ♦ Working voltage: 5V
- ♦ Low clamping voltage
- ♦ Low capacitance
- ♦ RoHS compliant transient protection for high speed data lines to IEC61000-4-2(ESD)±30kV(air),±25kV(contact)

Applications

- ♦ DVI & HDMI Port Protection
- ♦ Serial and Parallel Ports
- ♦ Projection TV
- ♦ Notebooks, Desktops, Servers
- ♦ High Speed Line : USB 1.0/2.0/3.0/3.1,VGA,DVI,SDI
- ♦ Portable instrumentation

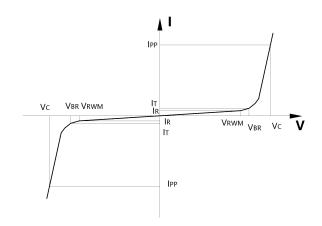
Mechanical data

- ♦ Lead finish:100% matte Sn(Tin)
- ♦ Mounting position: Any
- ♦ Qualified max reflow temperature:260°C
- ♦ Device meets MSL 1 requirements
- \Rightarrow Pure tin plating: $7 \sim 17$ um
- ♦ Pin flatness:≤3mil



• Electronic Parameter

Symbol	Parameter		
V_{RWM}	Peak Reverse Working Voltage		
I _R	Reverse Leakage Current @ V _{RWM}		
V _{BR}	Breakdown Voltage @ I _T		
I _T	Test Current		
I_{PP}	Maximum Reverse Peak Pulse Current		
V _C	Clamping Voltage @ IPP		
P _{PP}	Peak Pulse Power		
С	Junction Capacitance		



• Absolute maximum rating @TA=25°C

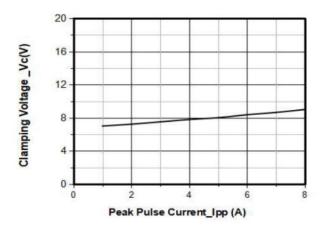
Symbol	Parameter	Value	Units		
P _{PP}	Peak Pulse Power (8/20μS	80	W		
Ірр	Peak Pulse Current (8/20µ	8	A		
V _{ESD}	ESD Rating per IEC61000-4-2:	Contact	25	KV	
		Air	30		
T _{STG}	Storage Temperature	-55/+150	°C		
T _J	Operating Temperature	-55/+150	°C		

• Electrical Characteristics @TA=25°C

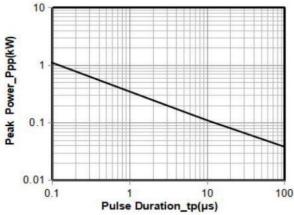
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}				5	V
Breakdown Voltage	V_{BR}	It = 1 mA	6			V
Reverse Leakage Current	I_R	VRWM =5.0V			0.1	μΑ
Clamping Voltage	$V_{\rm C}$	IPP = 1A, $tP = 8/20 \mu s$			8	V
Clamping Voltage	$V_{\rm C}$	IPP = $8A$, $tP = 8/20 \mu s$			10	V
Junction Capacitance	$C_{\rm J}$	VR=0V, f = 1MHz		14	20	pF



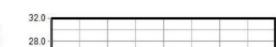
Typical Performance Characteristics

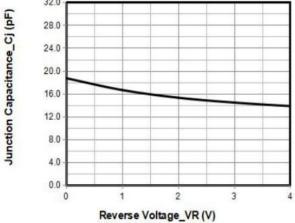


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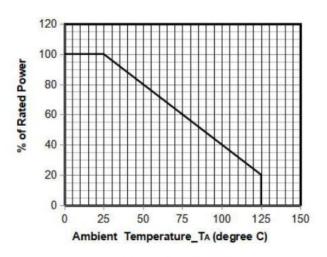


Junction Capacitance vs. Reverse Voltage

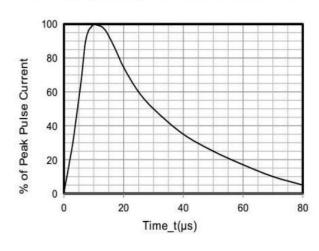




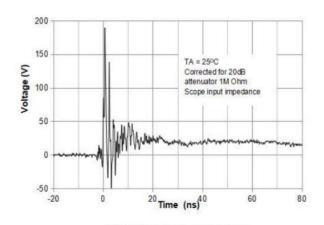
Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current



Power Derating Curve



8 X 20µs Pulse Waveform

ESD Clamping Voltage 8 kV Contact per IEC61000-4-2



• Package Information

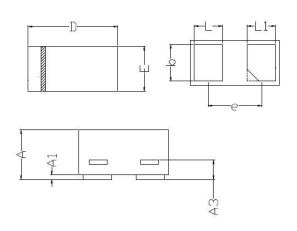
Ordering Information

Device	Package	Marking	Qty per Reel	Reel Size
SSCE5V022L1	DFN0603-2L	G	15,000pcs	7 Inch

Mechanical Data

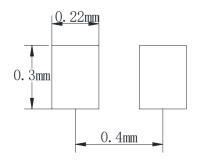
Case: DFN0603-2L

Case Material: Molded Plastic. UL Flammability



DIM	Millimeters			
DIIVI	Min	Max		
Α	0.230	0.330		
A1	0.000 0.050			
А3	0.102REF			
D	0.550	0.650		
E	0.250	0.350		
b	0.215 0.275			
L	0.12 0.23			
L1	0.12	0.23		
е	0.40BSC			

Recommended Pad outline





History Version

V2.0	Product datasheet	2020-07-21
V2.1	Update Electrical Characteristics	2022-04-07
	Update Typical Performance Characteristics	
	Add marking Icon	

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